

## SN74LVC125A-Q1 具有三态输出的汽车类四路 总线缓冲门

### 1 特性

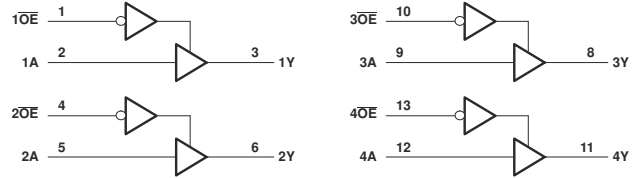
- 符合汽车应用要求
- 工作电压范围为 1.65V 至 3.6V
- 额定温度范围为  $-40^{\circ}\text{C}$  至  $125^{\circ}\text{C}$
- 输入电压高达 5.5V
- 电压为 3.3V 时,  $t_{pd}$  最大值为 4.8ns
- $V_{OLP}$  (输出接地反弹) 典型值小于 0.8V ( $V_{CC} = 3.3\text{V}$ 、 $T_A = 25^{\circ}\text{C}$  时)
- $V_{OHV}$  (输出  $V_{OH}$  下冲) 典型值大于 2V ( $V_{CC} = 3.3\text{V}$ 、 $T_A = 25^{\circ}\text{C}$  时)
- 门锁性能超过 250mA, 符合 JESD 17 规范

### 2 说明

这款四路总线缓冲门可在 1.65V 至 3.6V  $V_{CC}$  下运行。

器件型号	封装 <sup>(1)</sup>	封装尺寸 <sup>(2)</sup>	本体尺寸 <sup>(3)</sup>
SN74LVC125A-Q1	BQA ( WQFN , 14 )	3mm × 2.5mm	3mm × 2.5mm
	D ( SOIC , 14 )	8.65mm × 6mm	8.65mm × 3.91mm
	PW ( TSSOP , 14 )	5.00mm × 6.4mm	5.00mm × 4.40mm

- 有关更多信息, 请参阅第 10 节。
- 封装尺寸 (长 × 宽) 为标称值, 并包括引脚 (如适用)。
- 本体尺寸 (长 × 宽) 为标称值, 不包括引脚。



逻辑图 (正逻辑)



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### 3 Pin Configuration and Functions

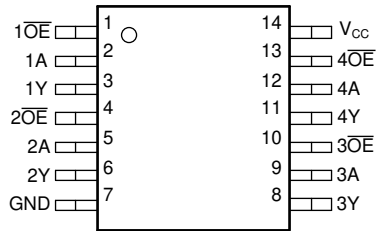


图 3-1. D Package, 14-Pin SOIC; PW Package, TSSOP-14 PIN (Top View)

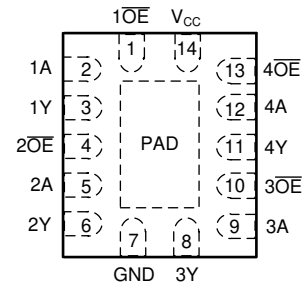


图 3-2. BQA Package, 14-Pin WQFN (Top View)

表 3-1. Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
1OE	1	Input	Output Enable
1A	2	Input	Input A
1Y	3	Output	Output Y
2OE	4	Input	Output Enable
2A	5	Input	Input A
2Y	6	Output	Output Y
GND	7	—	Ground
3Y	8	Output	Output Y
3A	9	Input	Input A
3OE	10	Input	Output Enable
4Y	11	Output	Output Y
4A	12	Input	Input A
4OE	13	Input	Output Enable
V <sub>CC</sub>	14	—	Positive Supply

## 4 Specifications

### 4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range	-0.5	6.5	V
V <sub>I</sub>	Input voltage range	-0.5	6.5	V
V <sub>O</sub>	Output voltage range <sup>(1) (2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50 mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50 mA
I <sub>O</sub>	Continuous output current			±50 mA
	Continuous current through V <sub>CC</sub> or GND			±100 mA
T <sub>stg</sub>	Storage temperature range	-65	150	°C
P <sub>tot</sub>	Power dissipation <sup>(3) (4)</sup>	T <sub>A</sub> = -40°C to 125°C		500 mW

(1) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(2) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.

(3) For the D package: above 70°C, the value of P<sub>tot</sub> derates linearly with 8 mW/K.

(4) For the PW package: above 60°C, the value of P<sub>tot</sub> derates linearly with 5.5 mW/K.

### 4.2 ESD Ratings

PARAMETER	DEFINITION	VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000
		Charged device model (CDM), per AEC Q100-011	±1000

(1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		T <sub>A</sub> = 25°C		-40°C to 125°C		UNIT	
		MIN	MAX	MIN	MAX		
V <sub>CC</sub>	Supply voltage	Operating	1.65	3.6	1.65	3.6	V
		Data retention only	1.5		1.5		
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 1.65V to 1.95V	0.65 × V <sub>CC</sub>		0.65 × V <sub>CC</sub>		V
		V <sub>CC</sub> = 2.3V to 2.7V	1.7		1.7		
		V <sub>CC</sub> = 2.7V to 3.6V	2		2		
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 1.65V to 1.95V	0.35 × V <sub>CC</sub>		0.35 × V <sub>CC</sub>		V
		V <sub>CC</sub> = 2.3V to 2.7V	0.7		0.7		
		V <sub>CC</sub> = 2.7V to 3.6V	0.8		0.8		
V <sub>I</sub>	Input voltage	0	5.5	0	5.5	V	
V <sub>O</sub>	Output voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V	
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.65V	-4		-4		mA
		V <sub>CC</sub> = 2.3V	-8		-8		
		V <sub>CC</sub> = 2.7V	-12		-12		
		V <sub>CC</sub> = 3V	-24		-24		
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65V	4		4		mA
		V <sub>CC</sub> = 2.3V	8		8		
		V <sub>CC</sub> = 2.7V	12		12		
		V <sub>CC</sub> = 3V	24		24		

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

	T <sub>A</sub> = 25°C		–40°C to 125°C		UNIT
	MIN	MAX	MIN	MAX	
Δt/Δv Input transition rise or fall rate		8		8	ns/V

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

#### 4.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>	BQA (WQFN)	D (SOIC)	PW (TSSOP)	UNIT
	14 PINS			
R <sub>θJA</sub> Junction-to-ambient thermal resistance	102.3	127.8	150.8	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

#### 4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C			–40°C to 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = –100μA	1.65V to 3.6 V	V <sub>CC</sub> – 0.2			V <sub>CC</sub> – 0.2		V
	I <sub>OH</sub> = –4mA	1.65V	1.29			1.1		
	I <sub>OH</sub> = –8mA	2.3V	1.9			1.75		
	I <sub>OH</sub> = –12mA	2.7V	2.2			2.1		
	I <sub>OH</sub> = –24mA	3V	2.4			2.35		
V <sub>OL</sub>	I <sub>OL</sub> = 100μA	1.65V to 3.6 V				0.1 0.2		V
	I <sub>OL</sub> = 4mA	1.65V				0.24 0.45		
	I <sub>OL</sub> = 8mA	2.3V				0.3 0.7		
	I <sub>OL</sub> = 12mA	2.7V				0.4 0.5		
	I <sub>OL</sub> = 24mA	3V				0.55 0.7		
I <sub>I</sub>	V <sub>I</sub> = 5.5 V or GND	3.6V				±1 ±10		μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	3.6V				±1 ±10		μA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	3.6V				1 20		μA
ΔI <sub>CC</sub>	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	2.7V to 3.6 V				500 500		μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.3V				5		pF

#### 4.6 Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see [Load Circuit and Voltage Waveforms](#))

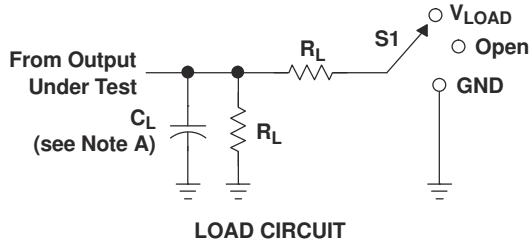
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	T <sub>A</sub> = 25°C			–40°C to 125°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	A	Y	2.7V	1	3	5.3	1	7	ns
			3.3V ± 0.3V	1	2.5	4.6	1	6	
t <sub>en</sub>	OE	Y	2.7V	1	3.3	6.4	1	8.5	ns
			3.3V ± 0.3V	1	2.4	5.2	1	7	
t <sub>dis</sub>	OE	Y	2.7V	1	2.5	4.8	1	6.5	ns
			3.3V ± 0.3V	1	2.4	4.4	1	6	
t <sub>sk(o)</sub>			3.3V ± 0.3V				1.5		ns

## 4.7 Operating Characteristics

$T_A = 25^\circ\text{C}$

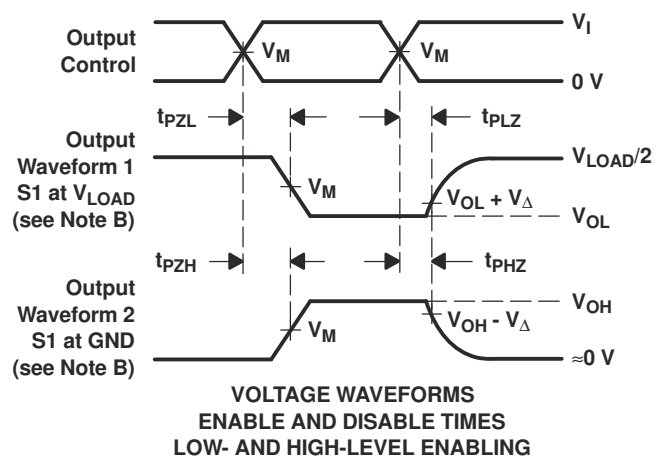
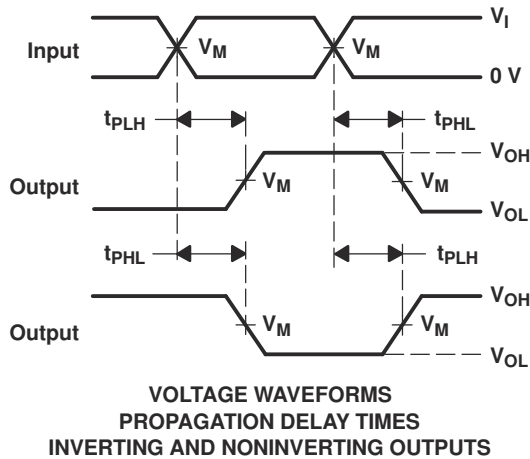
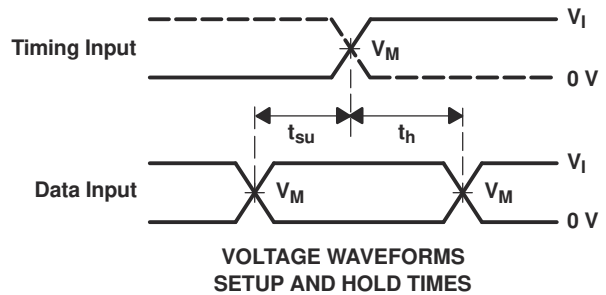
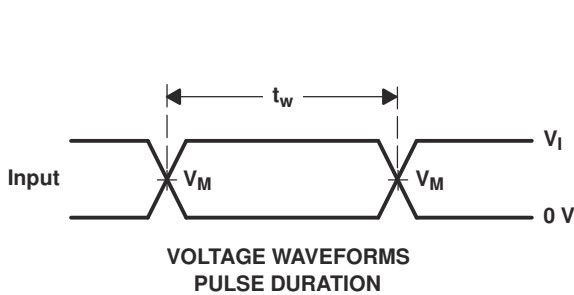
PARAMETER		TEST CONDITIONS	$V_{CC}$	TYP	UNIT
$C_{pd}$	Power dissipation capacitance per gate	f = 10MHz	3.3V	15	pF

## 5 Parameter Measurement Information



TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	$V_{LOAD}$
$t_{PHZ}/t_{PZH}$	GND

$V_{CC}$	INPUT		$V_M$	$V_{LOAD}$	$C_L$	$R_L$	$V_{\Delta}$
	$V_I$	$t_r/t_f$					
2.7 V	2.7 V	$\leq 2.5$ ns	1.5 V	6 V	50 pF	500 $\Omega$	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	$\leq 2.5$ ns	1.5 V	6 V	50 pF	500 $\Omega$	0.3 V



- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10$  MHz,  $Z_O = 50 \Omega$ .
  - The outputs are measured one at a time, with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - All parameters and waveforms are not applicable to all devices.

图 5-1. Load Circuit and Voltage Waveforms

## 6 Detailed Description

### 6.1 Overview

The SN74LVC125A features independent line drivers with 3-state outputs. Each output is disabled when the associated output-enable ( $\overline{\text{OE}}$ ) input is high.

To ensure the high-impedance state during power up or power down,  $\overline{\text{OE}}$  should be tied to  $V_{\text{CC}}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V system environment.

### 6.2 Functional Block Diagram

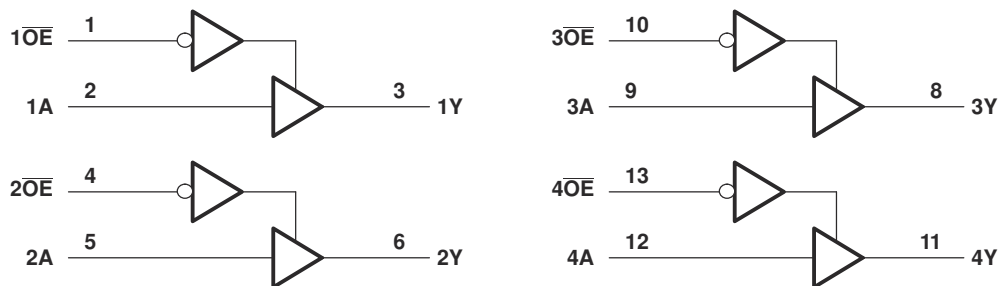


图 6-1. Logic Diagram (Positive Logic)

### 6.3 Device Functional Modes

Function Table  
(Each Buffer)

INPUTS		OUTPUT
$\overline{\text{OE}}$	A	Y
L	H	H
L	L	L
H	X	Z

## 7 Application and Implementation

### 备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

### 7.1 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the [节 4.3](#) table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu\text{F}$  is recommended; if there are multiple VCC pins, then 0.01  $\mu\text{F}$  or 0.022  $\mu\text{F}$  is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu\text{F}$  and a 1  $\mu\text{F}$  are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

### 7.2 Layout

#### 7.2.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in [节 7.2.2](#) are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient.

#### 7.2.2 Layout Example

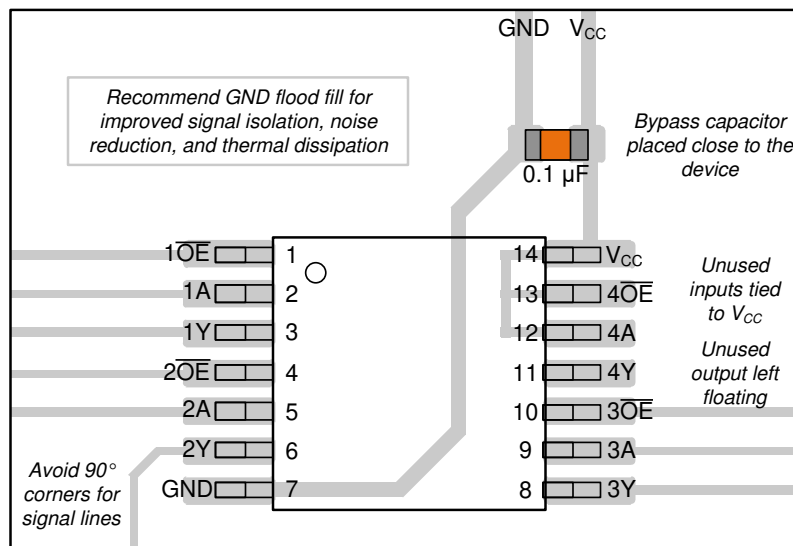


图 7-1. Example layout for the SN74LVC125A-Q1

## 8 Device and Documentation Support

### 8.1 Documentation Support (Analog)

#### 8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 8-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN74LVC125A-Q1	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 8.2 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](https://www.ti.com) 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

### 8.3 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

### 8.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

### 8.5 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

### 8.6 术语表

#### TI 术语表

本术语表列出并解释了术语、首字母缩略词和定义。

## 9 Revision History

### Changes from Revision D (May 2024) to Revision E (December 2024) Page

- Updated RθJA values: D = 86 to 127.8, all values in °C/W .....5

### Changes from Revision C (February 2024) to Revision D (May 2024) Page

- Updated RθJA values: PW = 113 to 150.8, all values in °C/W .....5

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">CLVC125AQPWRG4Q1</a>	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
CLVC125AQPWRG4Q1.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
<a href="#">SN74LVC125AQDRQ1</a>	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQDRQ1.A	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQDRQ1.B	Active	Production	SOIC (D)   14	2500   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
<a href="#">SN74LVC125AQPWRQ1</a>	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQPWRQ1.A	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
SN74LVC125AQPWRQ1.B	Active	Production	TSSOP (PW)   14	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125AQ
<a href="#">SN74LVC125AWBQARQ1</a>	Active	Production	WQFN (BQA)   14	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125Q
SN74LVC125AWBQARQ1.A	Active	Production	WQFN (BQA)   14	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	LC125Q

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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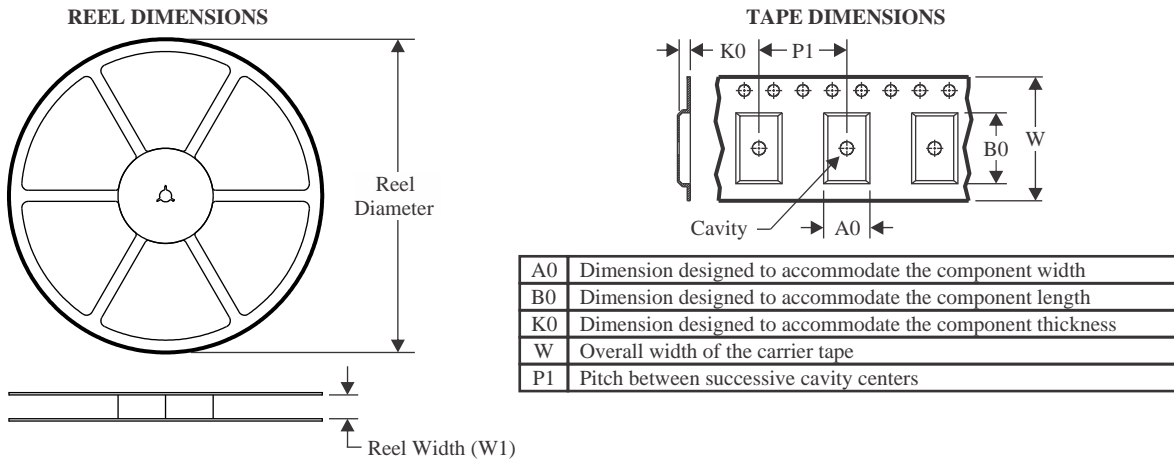
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF SN74LVC125A-Q1 :**

- Catalog : [SN74LVC125A](#)
- Enhanced Product : [SN74LVC125A-EP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Enhanced Product - Supports Defense, Aerospace and Medical Applications

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CLVC125AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CLVC125AQPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVC125AWBQARQ1	WQFN	BQA	14	3000	180.0	12.4	2.8	3.3	1.1	4.0	12.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CLVC125AQPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0
CLVC125AQPWRG4Q1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC125AQPWRQ1	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74LVC125AWBQARQ1	WQFN	BQA	14	3000	210.0	185.0	35.0

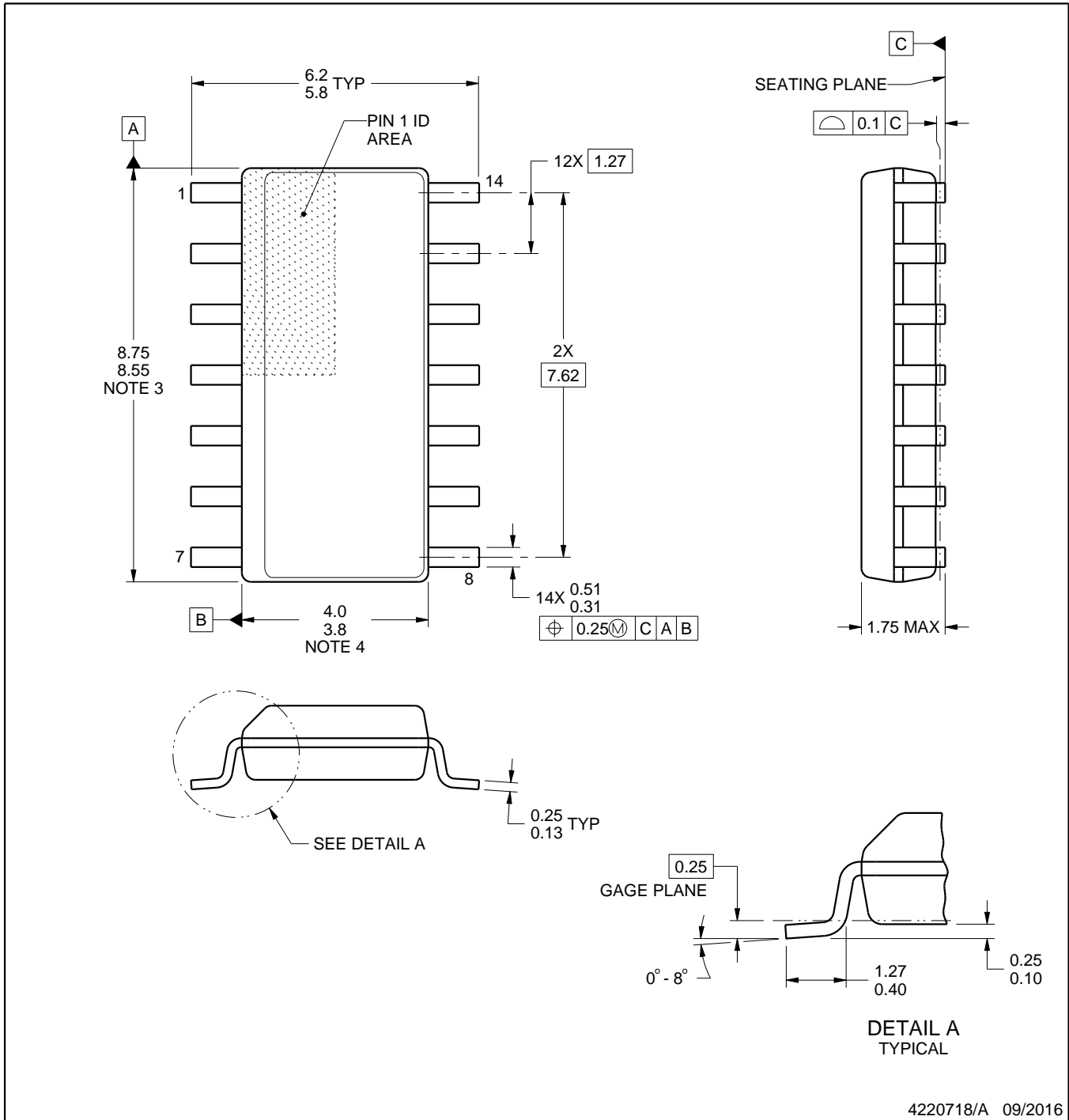
D0014A



# PACKAGE OUTLINE

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

# EXAMPLE BOARD LAYOUT

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

## GENERIC PACKAGE VIEW

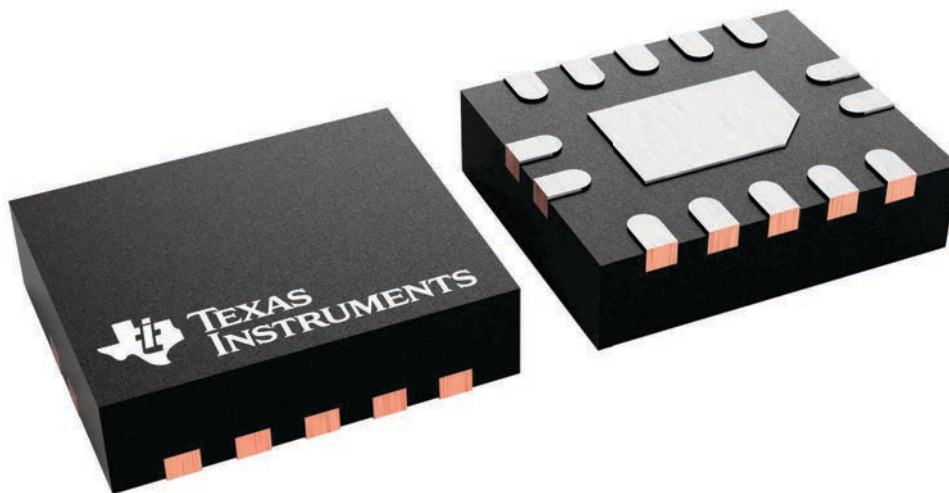
**BQA 14**

**WQFN - 0.8 mm max height**

2.5 x 3, 0.5 mm pitch

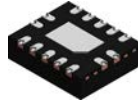
PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4227145/A

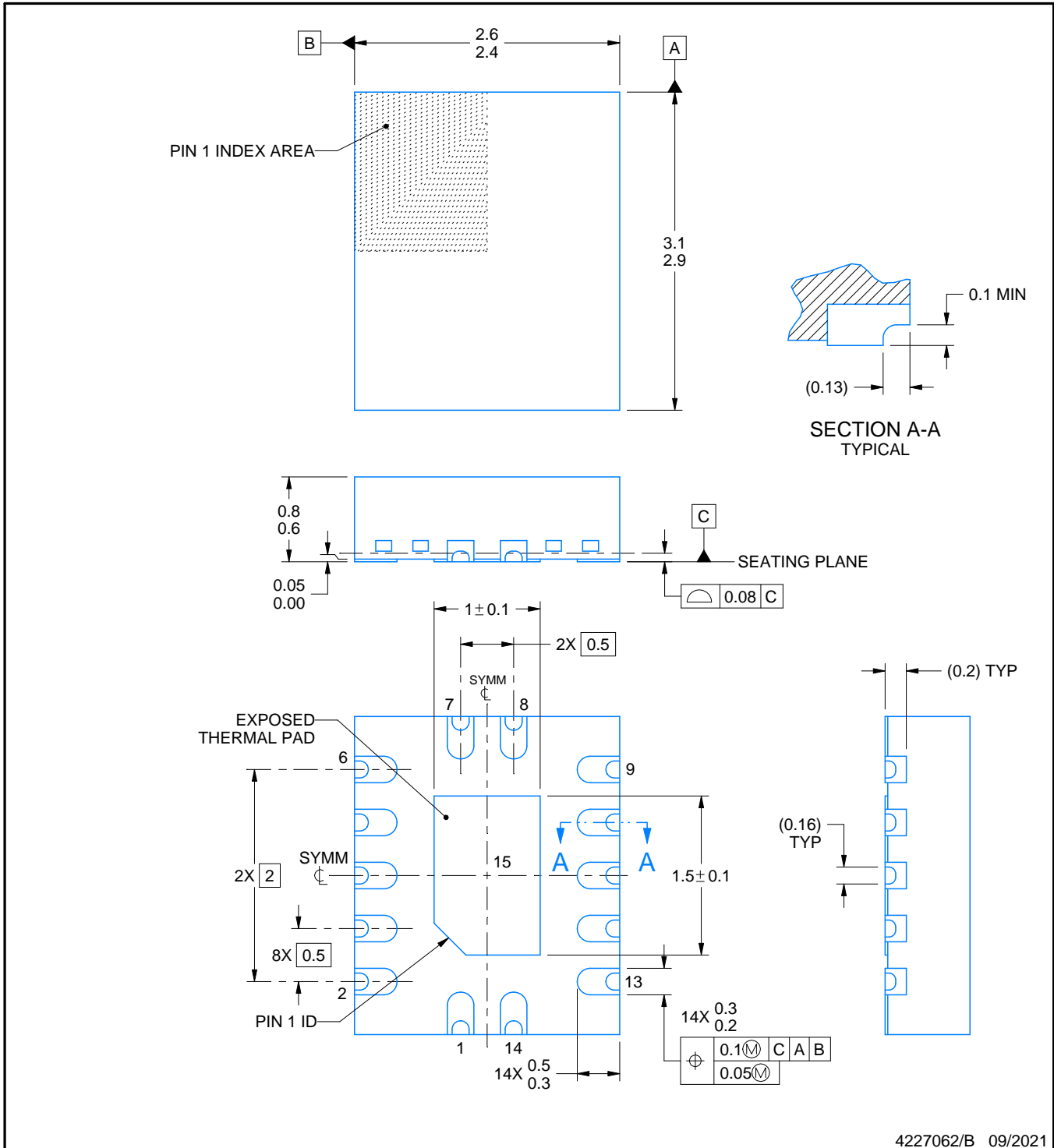
# BQA0014B



# PACKAGE OUTLINE

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



**NOTES:**

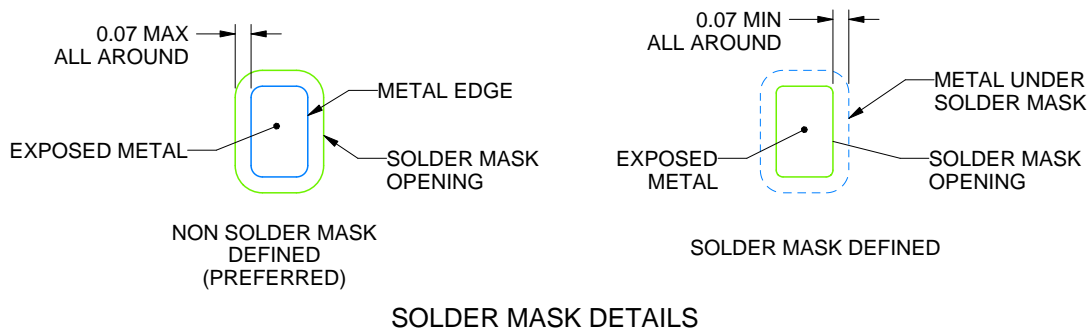
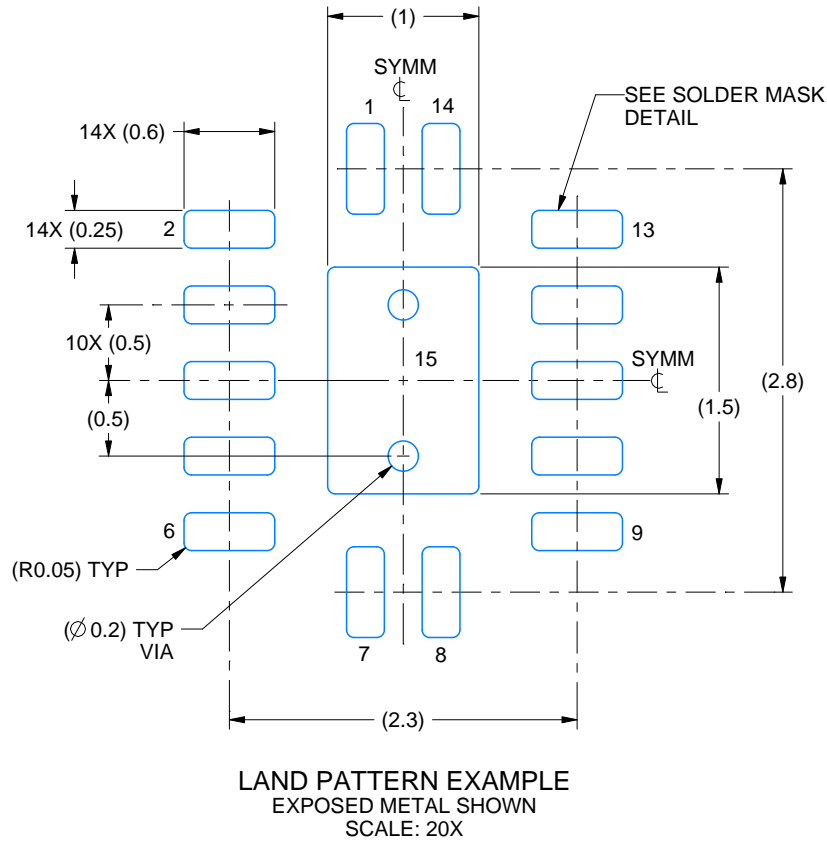
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

**BQA0014B**

**WQFN - 0.8 mm max height**

PLASTIC QUAD FLATPACK - NO LEAD



4227062/B 09/2021

NOTES: (continued)

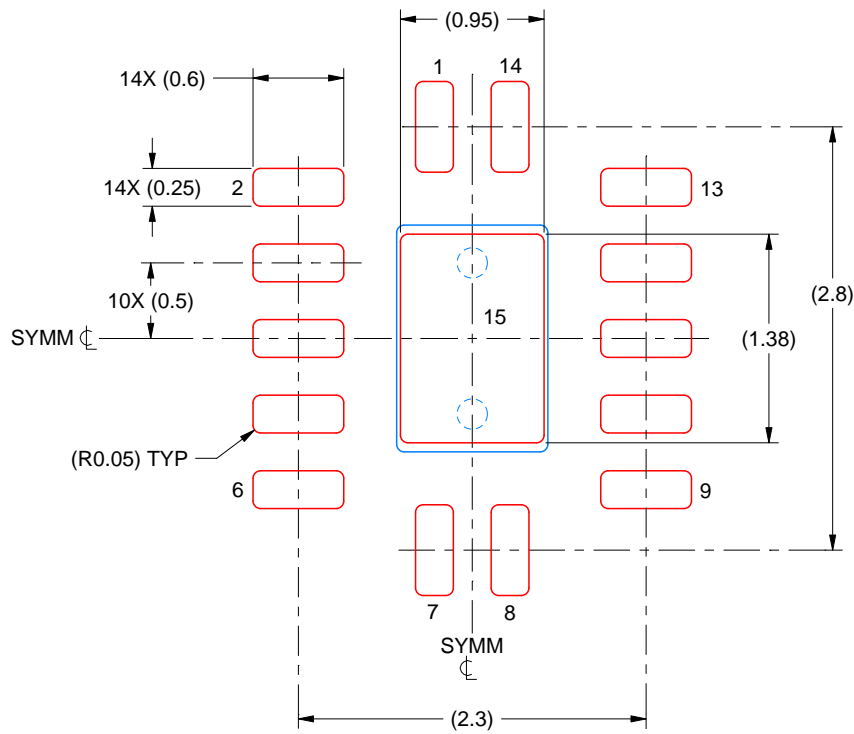
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

BQA0014B

WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE  
BASED ON 0.125 MM THICK STENCIL  
SCALE: 20X

EXPOSED PAD 15  
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE

4227062/B 09/2021

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

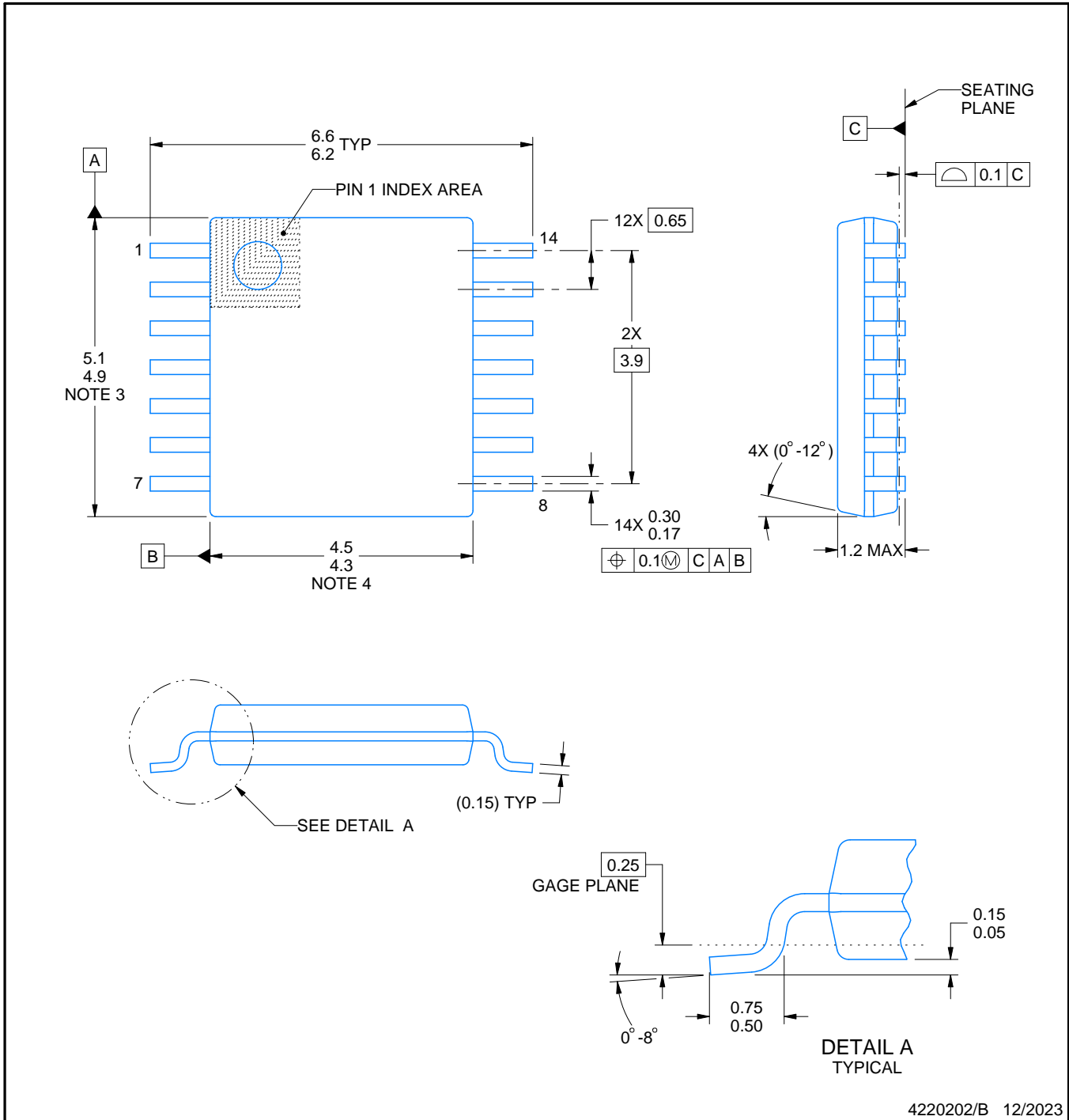
PW0014A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

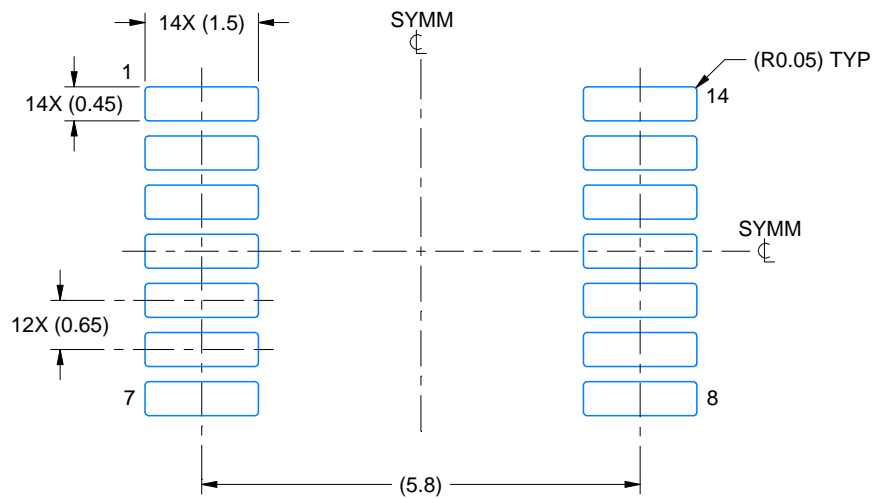
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

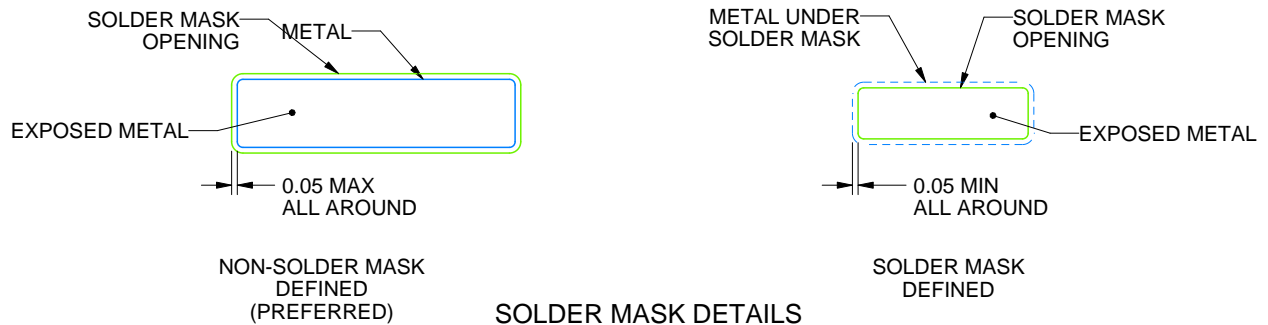
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 10X



4220202/B 12/2023

NOTES: (continued)

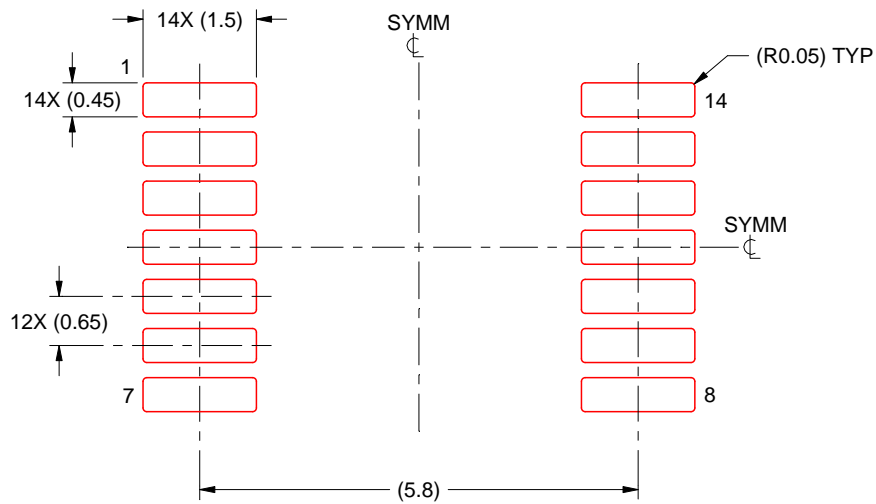
- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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